BLF6G20-110; BLF6G20LS-110

Power LDMOS transistor

AMPLEON

Rev. 4 — 1 September 2015

Product data sheet

1. Product profile

1.1 General description

110 W LDMOS power transistor for base station applications at frequencies from 1800 MHz to 2000 MHz.

Table 1. Typical performance

RF performance at $T_{case} = 25$ °C in a common source class-AB production test circuit.

Mode of operation	f	V _{DS}	P _{L(AV)}	Gp	η _D	IMD3	ACPR
	(MHz)	(V)	(W)	(dB)	(%)	(dBc)	(dBc)
2-carrier W-CDMA	1930 to 1990	28	25	19	32	-34 <mark>[1]</mark>	-38 <mark>[1]</mark>

^[1] Test signal: 3GPP; test model 1; 64 DPCH; PAR = 7 dB at 0.01 % probability on CCDF per carrier; carrier spacing 10 MHz.

CAUTION



This device is sensitive to ElectroStatic Discharge (ESD). Therefore care should be taken during transport and handling.

1.2 Features

- Typical 2-carrier W-CDMA performance at frequencies of 1930 MHz and 1990 MHz, a supply voltage of 28 V and an I_{Dq} of 900 mA:
 - ◆ Average output power = 25 W
 - Power gain = 19 dB
 - ◆ Efficiency = 32 %
 - ◆ IMD3 = -34 dBc
 - ◆ ACPR = -38 dBc
- Easy power control
- Integrated ESD protection
- Excellent ruggedness
- High efficiency
- Excellent thermal stability
- Designed for broadband operation (1800 MHz to 2000 MHz)
- Internally matched for ease of use
- Compliant to Directive 2002/95/EC, regarding Restriction of Hazardous Substances (RoHS)

1.3 Applications

■ RF power amplifiers for GSM, GSM EDGE, W-CDMA and CDMA base stations and multicarrier applications in the 1800 MHz to 2000 MHz frequency range

2. Pinning information

Table 2. Pinning

Pin	Description		Simplified outline	Graphic symbol
BLF6G20)-110 (SOT502A)			
1	drain			
2	gate			1 ,
3	source	<u>[1]</u>		2
				· 3 sym112
DI ECCO	DLS-110 (SOT502B)			3911112
DLF0G20				
1	drain			4
2	gate		3	, <u>, , , , , , , , , , , , , , , , , , </u>
3	source	[1]		2
				3
				sym112

^[1] Connected to flange.

3. Ordering information

Table 3. Ordering information

Type number	Package						
	Name	Description	Version				
BLF6G20-110	-	flanged LDMOST ceramic package; 2 mounting holes; 2 leads	SOT502A				
BLF6G20LS-110	-	earless flanged LDMOST ceramic package; 2 leads	SOT502B				

4. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{DS}	drain-source voltage		-	65	V
V_{GS}	gate-source voltage		-0.5	+13	V
I_D	drain current		-	29	Α
T_{stg}	storage temperature		-65	+150	°C
T _j	junction temperature		-	225	°C

5. Thermal characteristics

Table 5. Thermal characteristics

Symbol	Parameter	Conditions	Туре	Тур	Unit
R _{th(j-case)}	thermal resistance from	T_{case} = 80 °C;	BLF6G20-110	0.52	K/W
	junction to case	$P_L = 25 W (CW)$	BLF6G20LS-110	0.45	K/W

6. Characteristics

Table 6. Characteristics

 $T_i = 25$ °C unless otherwise specified.

,	<u> </u>					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{(BR)DSS}	drain-source breakdown voltage	$V_{GS} = 0 \text{ V}; I_D = 0.5 \text{ mA}$	65	-	-	V
$V_{GS(th)}$	gate-source threshold voltage	V_{DS} = 10 V; I_{D} = 150 mA	1.4	2	2.4	V
V_{GSq}	gate-source quiescent voltage	V_{DS} = 28 V; I_{D} = 950 mA	1.6	2.1	2.6	V
I _{DSS}	drain leakage current	$V_{GS} = 0 \text{ V}; V_{DS} = 28 \text{ V}$	-	-	5	μА
I _{DSX}	drain cut-off current	$V_{GS} = V_{GS(th)} + 3.75 V;$ $V_{DS} = 10 V$	22.3	27	-	Α
I _{GSS}	gate leakage current	$V_{GS} = 13 \text{ V}; V_{DS} = 0 \text{ V}$	-	-	450	nΑ
g _{fs}	forward transconductance	V_{DS} = 10 V; I_{D} = 7.5 A	-	10.5	-	S
R _{DS(on)}	drain-source on-state resistance	$V_{GS} = V_{GS(th)} + 3.75 V;$ $I_D = 5.25 A$	-	0.1	0.160	Ω
C _{rs}	feedback capacitance	$V_{GS} = 0 \text{ V}; V_{DS} = 28 \text{ V};$ f = 1 MHz	-	2.1	-	pF

7. Application information

Table 7. Application information

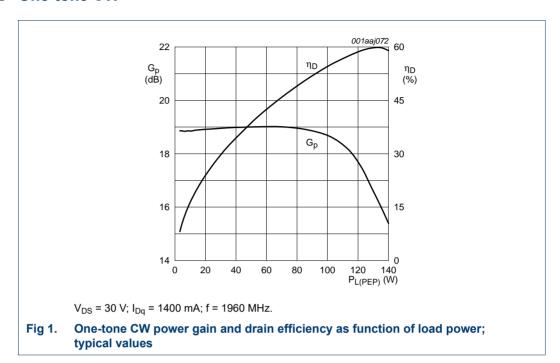
Mode of operation: 2-carrier W-CDMA; PAR 7 dB at 0.01 % probability on CCDF; 3GPP test model 1; 1-64 PDPCH; f_1 = 1932.5 MHz; f_2 = 1942.5 MHz; f_3 = 1977.5 MHz; f_4 = 1987.5 MHz; RF performance at V_{DS} = 28 V; I_{Dq} = 900 mA; T_{case} = 25 °C; unless otherwise specified; in a class-AB production test circuit.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$P_{L(AV)}$	average output power		-	25	-	W
Gp	power gain	$P_{L(AV)} = 25 W$	18	19	-	dB
η_{D}	drain efficiency	$P_{L(AV)} = 25 W$	28	32	-	%
IMD3	third order intermodulation distortion	$P_{L(AV)} = 25 W$	-	-34	-28	dBc
ACPR	adjacent channel power ratio	$P_{L(AV)} = 25 \text{ W}$	-	-38	-33	dBc

7.1 Ruggedness in class-AB operation

The BLF6G20-110 and BLF6G20LS-110 are capable of withstanding a load mismatch corresponding to VSWR = 10 : 1 through all phases under the following conditions: $V_{DS} = 28 \text{ V}$; $I_{Dq} = 900 \text{ mA}$; $P_L = 110 \text{ W}$ (CW); f = 1990 MHz.

7.2 One-tone CW



7.3 Two-tone CW

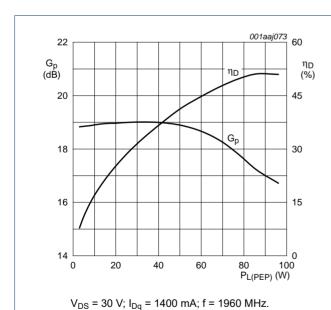
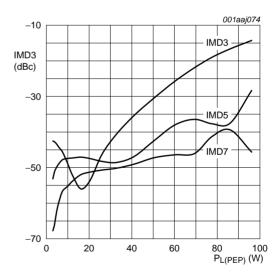


Fig 2. Two-tone CW power gain and drain efficiency as function of peak envelope load power; typical values

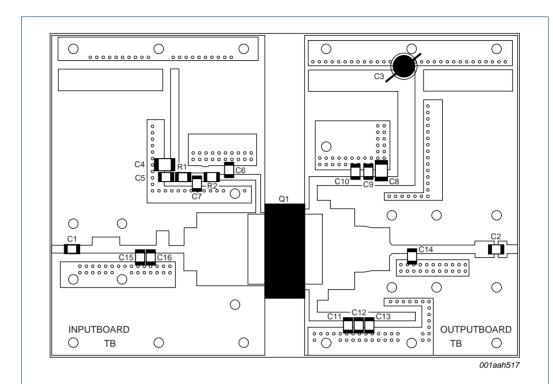


 V_{DS} = 30 V; I_{Dq} = 1400 mA; f = 1960 MHz.

Fig 3. Two-tone CW intermodulation distortion as a function of peak envelope load power; typical values

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8. Test information



The striplines are on a double copper-clad Taconic RF35 Printed-Circuit Board (PCB) with ϵ_{r} = 3.5 and thickness = 0.76 mm.

See Table 8 for list of components.

Fig 4. Component layout

Table 8. List of components (see Figure 4).

Component	Description	Value	Remarks
C1	multilayer ceramic chip capacitor	8.2 pF	<u>[1]</u>
C2	multilayer ceramic chip capacitor	10 pF	<u>[1]</u>
C3	electrolytic capacitor	100 μF; 63 V	
C4, C8	multilayer ceramic chip capacitor	$4.7~\mu F; 25~V$	[2]
C5, C7, C12, C13	multilayer ceramic chip capacitor	220 nF; 50 V	[3]
C6, C10, C11	multilayer ceramic chip capacitor	13 pF	[1]
C9	multilayer ceramic chip capacitor	330 nF; 50 V	<u>[3]</u>
C14	multilayer ceramic chip capacitor	1.0 pF	[1]
C15	multilayer ceramic chip capacitor	1.5 pF	[1]
C16	multilayer ceramic chip capacitor	0.6 pF	[1]
Q1	BLF6G20-110 or BLF6G20LS-110	-	
R1	SMD resistor	1.0 Ω	
R2	SMD resistor	2.7 Ω	

^[1] American Technical Ceramics type 100B or capacitor of same quality.

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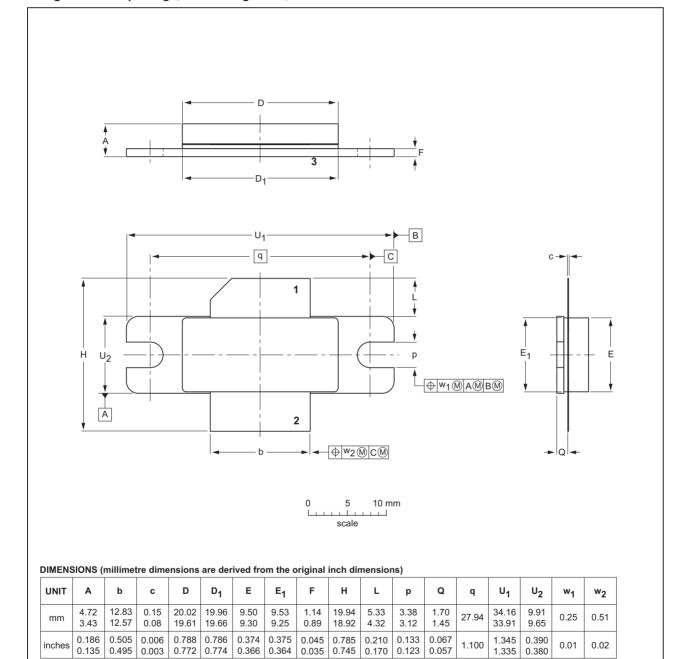
^[2] TDK or capacitor of same quality.

^[3] AVX or capacitor of same quality.

9. Package outline

Flanged ceramic package; 2 mounting holes; 2 leads

SOT502A

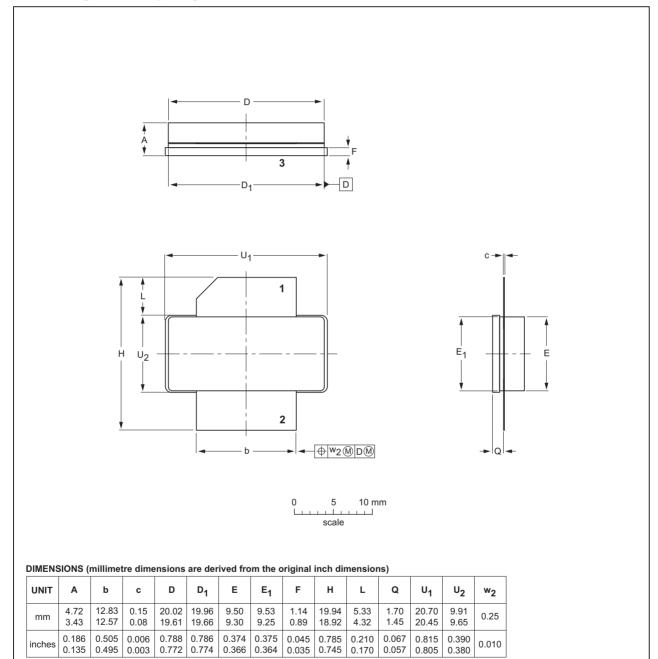


OUTLINE		REFERENCES			EUROPEAN ISSUE DAT		
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE	
SOT502A					$ \ \ \bigoplus \bigoplus$	-03-01-10- 12-05-02	

Fig 5. Package outline SOT502A

Earless flanged ceramic package; 2 leads

SOT502B



OUTLINE	REFERENCES			EUROPEAN ISSUE DATE		
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE
SOT502B						-07-05-09 12-05-02

Fig 6. Package outline SOT502B

10. Abbreviations

Table 9. Abbreviations

Acronym	Description
3GPP	Third Generation Partnership Project
CCDF	Complementary Cumulative Distribution Function
CDMA	Code Division Multiple Access
CW	Continuous Wave
DPCH	Dedicated Physical CHannel
EDGE	Enhanced Data rates for GSM Evolution
EVM	Error Vector Magnitude
GSM	Global System for Mobile communications
LDMOS	Laterally Diffused Metal-Oxide Semiconductor
LDMOST	Laterally Diffused Metal-Oxide Semiconductor Transistor
PAR	Peak-to-Average power Ratio
PDPCH	transmission Power of the Dedicated Physical CHannel
RF	Radio Frequency
SMD	Surface Mounted Device
VSWR	Voltage Standing-Wave Ratio
W-CDMA	Wideband Code Division Multiple Access
-	

11. Revision history

Table 10. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes		
BLF6G20-110_BLF6G20LS-110#4	20150901	Product data sheet	-	BLF6G20-110_BLF6G20LS-110_3		
Modifications:	 The format of this document has been redesigned to comply with the new identity guidelines of Ampleon. Legal texts have been adapted to the new company name where appropriate. 					
BLF6G20-110_BLF6G20LS-110_3	20090113	Product data sheet	-	BLF6G20-110_BLF6G20LS-110_2		
BLF6G20-110_BLF6G20LS-110_2	20081117	Product data sheet	-	BLF6G20-110_BLF6G20LS-110_1		
BLF6G20-110_BLF6G20LS-110_1	20080128	Preliminary data sheet	-	-		

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Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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